SnapLED

PRELIMINARY SPEC

Part Number: WP7701C4VGC/Z



Features:

*HIGH LUMINANCE OUTPUT.
*DESIGN FOR HIGH CURRENT OPERATION.
*SOLDERLESS MOUNTING TECHNIQUE.
*LOW POWER CONSUMPTION.
*LOW THERMAL RESISTANCE.
*LOW PROFILE.
*PACKAGED IN TUBES FOR USE WITH AUTOMATIC
INSERTION EQUIPMENT.
*RoHS COMPLIANT.

Technical Data



ATTENTION OBSERVE PRECAUTIONS FOR HANDLING ELECTROSTATIC DISCHARGE

SENSITIVE DEVICES

Description

Static electricity and surge damage the LEDS. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. All devices, equipment and machinery must be electrically grounded.

Benefits:

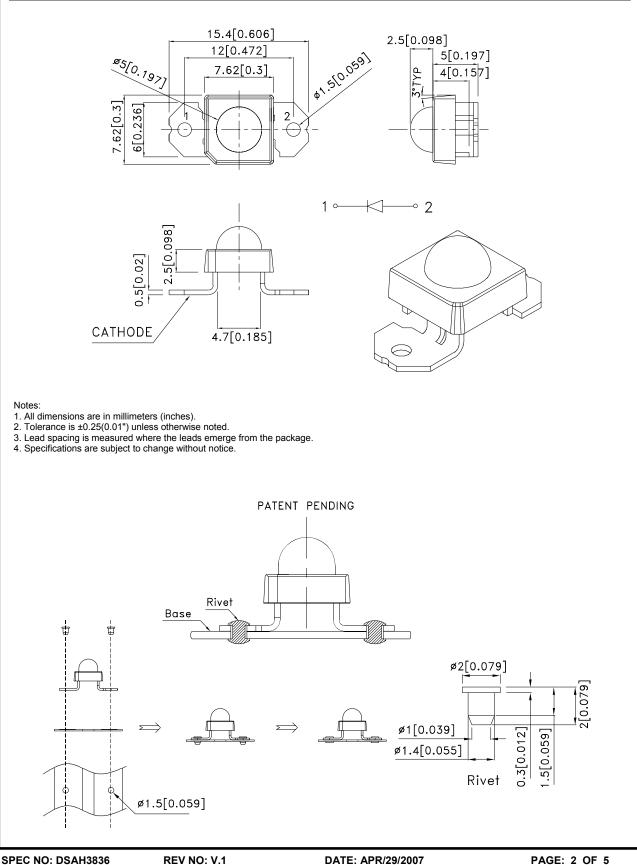
- *Rugged Lighting Products.
- *Electricity savings.
- *Maintenance savings.
- *Environmental Conformance.

Typical Applications:

- *Automotive Exterior Lighting.
- *Solid State Lighting and Signaling.



Outline Drawings



SPEC NO: DSAH3836 APPROVED: WYNEC CHECKED: Allen Liu

DATE: APR/29/2007 DRAWN: Y.L.LI

ARAMETER			VG/Z		UNITS
C Forward Current			50		mA
Power dissipation			210		mW
Reverse Voltage			5		V
Operating Temperature			-40 To +85		C
Storage Temperature			-55 To +85		۵°
Selection Guide					
Part No.	LED COLC			lv(cd)[1] @50mA in. Typ.	Viewing Angle[2 201/2 Typ.
WP7701C4VGC/Z		Green (InGa	aN) 5	.7 9.5	50°
		PFAK		NT[1]	SPECTRAL LINE
DEVICE		PEAK /ELENGTH	DOMINAN		SPECTRAL LINE WAVELENGTH
DEVICE TYPE	WAV			NGTH nm)	-
TYPE VG/Z	WAV	/ELENGTH EAK (nm)	WAVELEM λDOM (ι	NGTH nm)	WAVELENGTH Δλ1/2(nm)
TYPE VG/Z Note: The dominant wavelength is Electrical Character DEVICE	WAV λPI derived from the ristics at TA FORWARD VF (V	YELENGTH EAK (nm) TYP. 525 e CIE Chromaticity D	WAVELEN λDOM (ι TYP.	NGTH nm) erceived color of the devic	WAVELENGTH Δλ1/2(nm) TYP. 39 ce; Wavelength: +/-1nm. E THERMAL RESISTANCE Rθj -pin
TYPE VG/Z lote: .The dominant wavelength is	WAV λPI derived from the ristics at TA FORWARD VF (V	YELENGTH EAK (nm) TYP. 525 CIE Chromaticity D A=25°C VOLTAGE [1] OLTS) @	WAVELEN λDOM (i TYP. 535 Diagram and represents the per Diagram and t	NGTH nm) erceived color of the devic CAPACITANCE C (pF) @	WAVELENGTH Δλ1/2(nm) TYP. 39 ce; Wavelength: +/-1nm. E THERMAL RESISTANCE Rθj -pin
TYPE VG/Z Note: .The dominant wavelength is Electrical Character DEVICE	WAV API derived from the ristics at TA FORWARD VF (V IF=5	YELENGTH EAK (nm) TYP. 525 CIE Chromaticity D A=25°C VOLTAGE [1] (OLTS) @ 50mA	WAVELEN ADOM (i TYP. 535 Diagram and represents the per REVERSE CURRENT IR (uA) @ VR=5V	CAPACITANCE C (pF) VF=0V F=1MHZ	WAVELENGTH Δλ1/2(nm) TYP. 39 ce; Wavelength: +/-1nm. E THERMAL RESISTANCE Rθj -pin °C/W
TYPE VG/Z Note: I.The dominant wavelength is Electrical Character DEVICE TYPE	WAV API	YELENGTH EAK (nm) TYP. 525 CIE Chromaticity D A=25°C VOLTAGE [1] OLTS) @ 50mA MAX.	WAVELEN ADOM (i TYP. 535 Diagram and represents the per REVERSE CURRENT IR (uA) @ VR=5V MAX.	CAPACITANCE CAPACITANCE C (pF) WF=0V F=1MHZ TYP.	WAVELENGTH Δλ1/2(nm) TYP. 39 ce; Wavelength: +/-1nm. E THERMAL RESISTANCE Rθj -pin °C/W TYP.
TYPE VG/Z Note:The dominant wavelength is Electrical Character DEVICE TYPE VG/Z Note:	WAV API	YELENGTH EAK (nm) TYP. 525 CIE Chromaticity D A=25°C VOLTAGE [1] @ 50mA MAX. 4.2	WAVELEN ADOM (i TYP. 535 Diagram and represents the per REVERSE CURRENT IR (uA) @ VR=5V MAX.	CAPACITANCE C (pF) VF=0V F=1MHZ TYP. 65	WAVELENGTH Δλ1/2(nm) TYP. 39 ce; Wavelength: +/-1nm. E THERMAL RESISTANCE Rθj -pin °C/W TYP.



